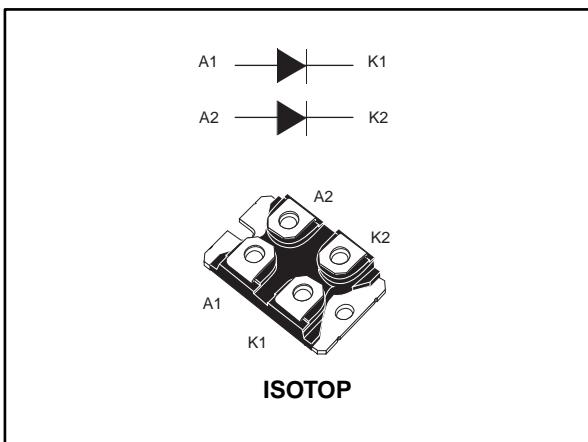


## Turbo 2 ultrafast high voltage rectifier

Datasheet - production data



### Features

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces switching and conduction losses
- Insulated package ISOTOP:
  - Insulated voltage: 2500 V<sub>RMS</sub> sine

### Description

This device that uses ST Turbo 2 600 V technology, is specially suited for use in switching power supplies, and industrial applications, as rectification and freewheeling diode.

**Table 1: Device summary**

Symbol	Value
I <sub>F(AV)</sub>	2 x 60 A
V <sub>RRM</sub>	600 V
T <sub>j</sub> (max.)	150 °C
V <sub>F</sub> (typ.)	0.95 V
t <sub>rr</sub> (max.)	70 ns



TM: ISOTOP is a trademark of  
STMicroelectronics

# 1 Characteristics

Table 2: Absolute ratings (limiting values, per diode)

Symbol	Parameter		Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage		600	V
$I_{F(RMS)}$	Forward rms current		120	A
$I_{F(AV)}$	Average forward current, $\delta = 0.5$		60	A
$I_{FSM}$	Surge non repetitive forward current	$t_p = 10 \text{ ms sinusoidal}$	500	A
$T_{stg}$	Storage temperature range		-55 to +150	°C
$T_j$	Maximum operating junction temperature		150	°C

Table 3: Thermal parameters

Symbol	Parameter		Maximum values	Unit
$R_{th(j-c)}$	Junction to case	Per diode	0.98	°C/W
		Total	0.54	
$R_{th(c)}$	Coupling		0.1	

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_j (\text{diode1}) = P_{(\text{diode1})} \times R_{th(j-c)} \text{ (per diode)} + P_{(\text{diode2})} \times R_{th(c)}$$

Table 4: Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25 \text{ °C}$	$V_R = V_{RRM}$	-		50	$\mu\text{A}$
		$T_j = 125 \text{ °C}$		-	50	500	
$V_F^{(2)}$	Forward voltage drop	$T_j = 25 \text{ °C}$	$I_F = 60 \text{ A}$	-		1.55	V
		$T_j = 150 \text{ °C}$		-	0.95	1.20	

## Notes:

(<sup>1</sup>)Pulse test:  $t_p = 5 \text{ ms}$ ,  $\delta < 2\%$

(<sup>2</sup>)Pulse test:  $t_p = 380 \text{ } \mu\text{s}$ ,  $\delta < 2\%$

To evaluate the maximum conduction losses, use the following equation:

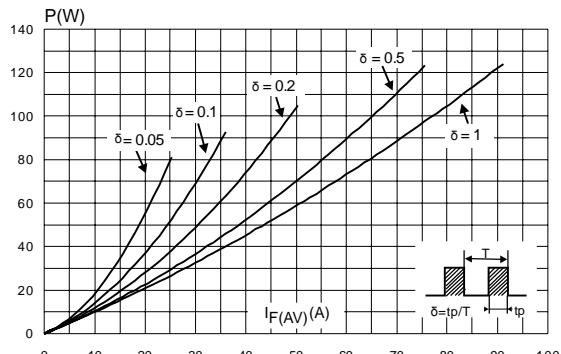
$$P = 0.93 \times I_{F(AV)} + 0.0045 \times I_{F^2(RMS)}$$

Table 5: Dynamic characteristics (per diode)

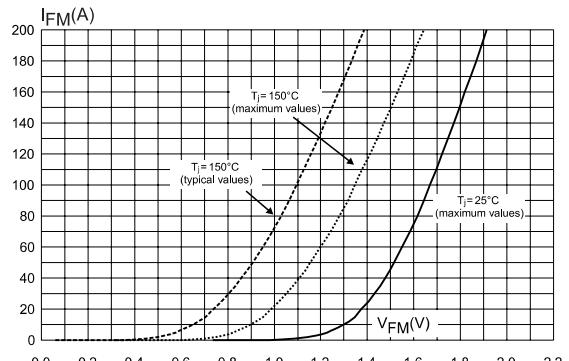
Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit	
$t_{rr}$	Reverse recovery time	$T_j = 25^\circ\text{C}$	$I_F = 0.5 \text{ A},$ $I_{rr} = 0.25 \text{ A},$ $I_R = 1 \text{ A}$	-		70	ns
			$I_F = 1 \text{ A},$ $dI_F/dt = 50 \text{ A}/\mu\text{s},$ $V_R = 30 \text{ V}$	-	75	105	
$I_{RM}$	Reverse recovery current	$T_j = 125^\circ\text{C}$	$I_F = 60 \text{ A},$ $dI_F/dt = 400 \text{ A}/\mu\text{s},$ $dI_F/dt = 100 \text{ A}/\mu\text{s}$	-	14	19	A
$t_{fr}$	Forward recovery time	$T_j = 25^\circ\text{C}$	$I_F = 60 \text{ A},$ $dI_F/dt = 200 \text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \times V_{F\max}$	-		500	ns
$V_{FP}$	Forward recovery voltage	$T_j = 25^\circ\text{C}$	$I_F = 60 \text{ A},$ $dI_F/dt = 200 \text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \times V_{F\max}$	-	3		V

## 1.1 Characteristics (curves)

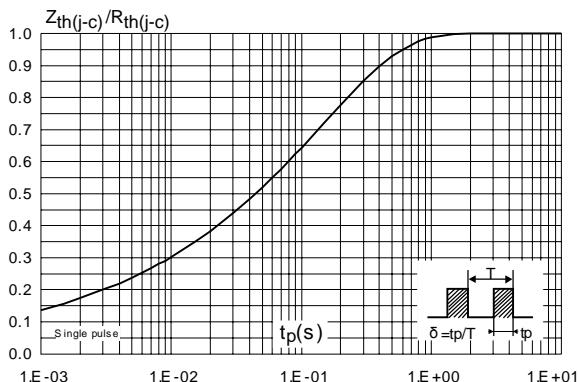
**Figure 1: Conduction losses versus average forward current (per diode)**



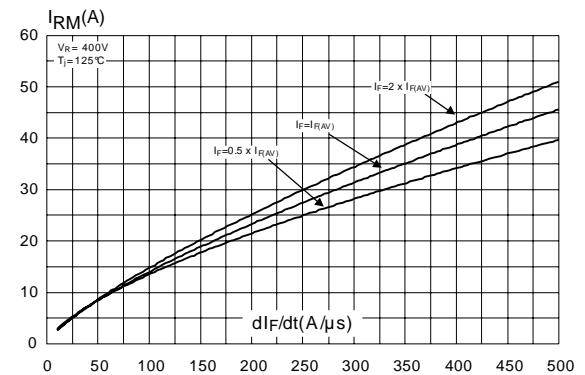
**Figure 2: Forward voltage drop versus forward current (per diode)**



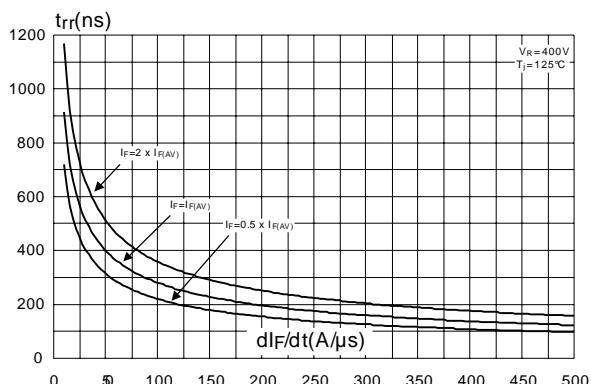
**Figure 3: Relative variation of thermal impedance junction to case versus pulse duration**



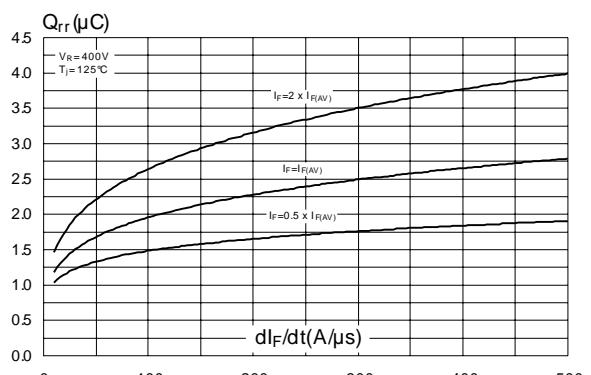
**Figure 4: Peak reverse recovery current versus dI<sub>F</sub>/dt (typical values, per diode)**

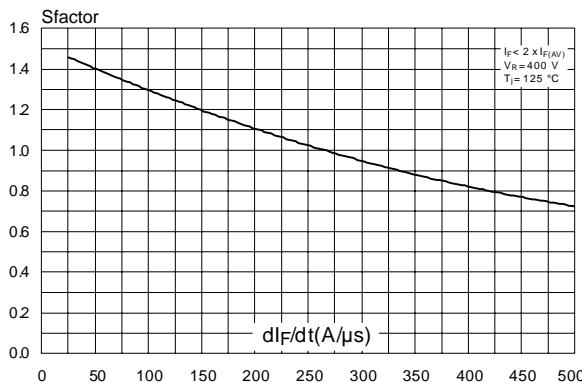
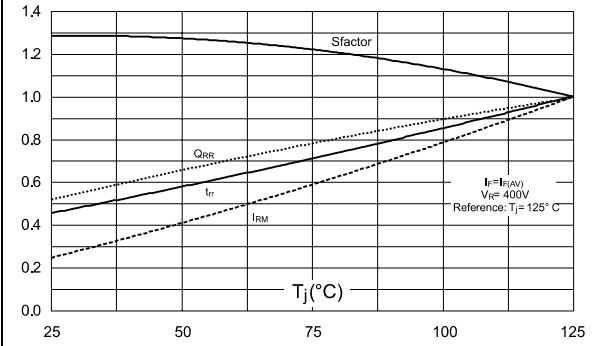
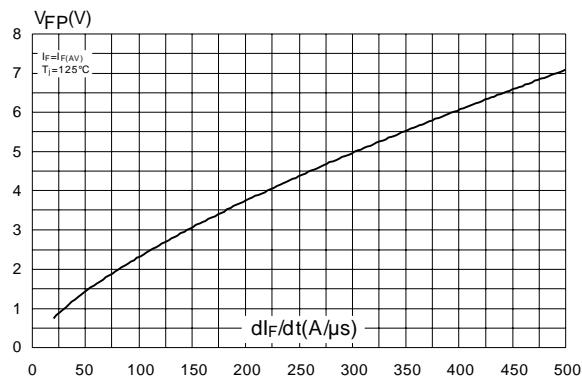
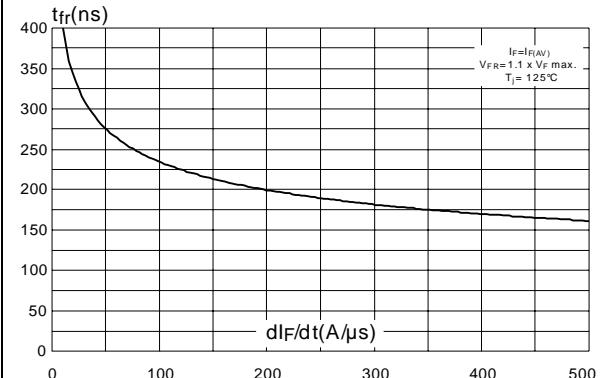
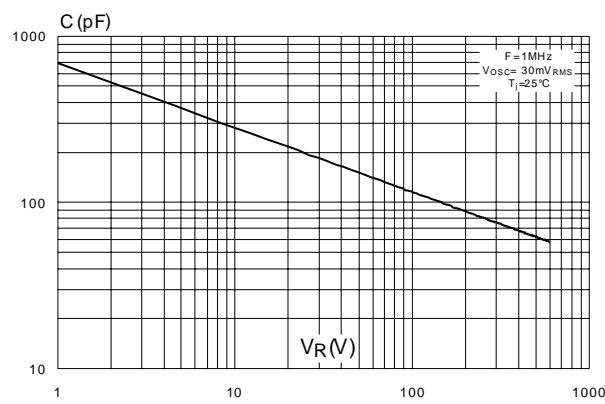


**Figure 5: Reverse recovery time versus dI<sub>F</sub>/dt (typical values, per diode)**



**Figure 6: Reverse recovery charges versus dI<sub>F</sub>/dt (typical values, per diode)**



**Figure 7: Reverse recovery softness factor versus  $dI_F/dt$  (typical values, per diode)****Figure 8: Relative variations of dynamic parameters versus junction temperature****Figure 9: Transient peak forward voltage versus  $dI_F/dt$  (typical values, per diode)****Figure 10: Forward recovery time versus  $dI_F/dt$  (typical values, per diode)****Figure 11: Junction capacitance versus reverse voltage applied (typical values, per diode)**

## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).  
ECOPACK® is an ST trademark.

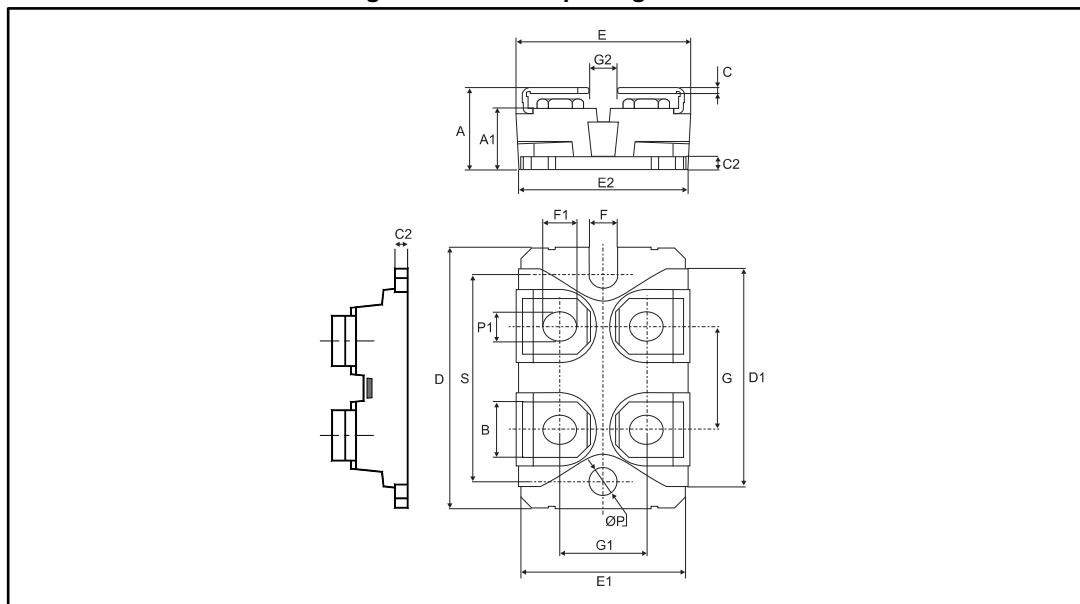
- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 1.3 N·m
- Maximum torque value: 1.5 N·m

STMicroelectronics strongly recommend the use of the screws delivered with this product.

The use of any other screws is entirely at the user's own risk and will invalidate the warranty.

### 2.1 ISOTOP package information

Figure 12: ISOTOP package outline



**Table 6: ISOTOP package mechanical data**

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	11.80	12.20	0.460	0.480
A1	8.90	9.10	0.350	0.358
B	7.80	8.20	0.307	0.323
C	0.75	0.85	0.030	0.033
C2	1.95	2.05	0.077	0.081
D	37.80	38.20	1.488	1.504
D1	31.50	31.70	1.240	1.248
E	25.15	25.50	0.990	1.004
E1	23.85	24.15	0.939	0.951
E2	24.80		0.976	
G	14.90	15.10	0.587	0.594
G1	12.60	12.80	0.496	0.504
G2	3.50	4.30	0.138	0.169
F	4.10	4.30	0.161	0.169
F1	4.60	5	0.181	0.197
Diam P	4	4.30	0.157	0.69
P1	4	4.40	0.157	0.173
S	30.10	30.30	1.185	1.193

### 3 Ordering information

Table 7: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STTH120L06TV1	STTH120L06TV1	ISOTOP	27 g (without screws)	10 (with screws)	Tube

### 4 Revision history

Table 8: Document revision history

Date	Revision	Changes
07-Sep-2004	1	First issue.
04-Apr-2011	2	Updated <i>Chapter 2: Package information..</i>
20-Jan-2017	3	Updated <i>Section "Features"</i> and <i>Section 2.2: "ISOTOP package information"</i> .

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